



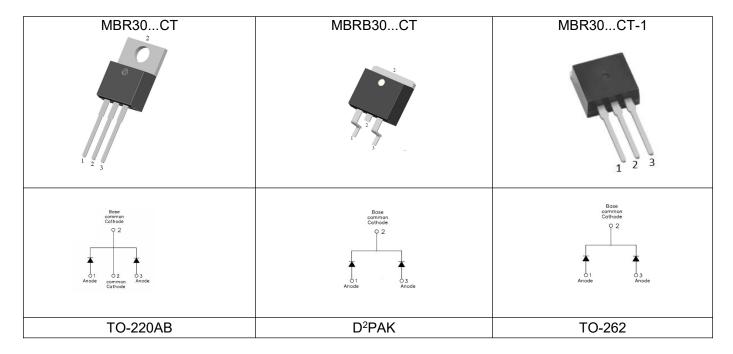
# MBR3035/3045CT MBRB3035/3045CT MBR3035/3045CT-1 SCHOTTKY RECTIFIER

#### **Features**

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: 100% Pure Tin
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Applications**

Switching power supply Converters Free-Wheeling diodes Reverse battery protection



# **Maximum Ratings:**

Characteristics	Symbol	Condition		Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V <sub>RRM</sub> V <sub>RWM</sub>	-	35	MBR3035CT	W
DC Blocking Voltage	V RWM VR		45	MBR3045CT	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=123°C, rectangular wave form		15(Per Leg) 0(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse, T <sub>C</sub> = 25 °C		240	А

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### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	$V_{F1}$	@ 15A, Pulse, T <sub>J</sub> = 25 °C	0.66	0.70	V
(Per Leg)*	$V_{F2}$	@ 15A, Pulse, T <sub>J</sub> = 125 °C	0.55	0.57	V
Reverse Current (Per Leg)*	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25  ^{\circ}\text{C}$	0.3	1.0	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 100  ^{\circ}\text{C}$	1	40	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	543	800	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

 $<sup>^*</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2%

# **Thermal-Mechanical Specifications:**

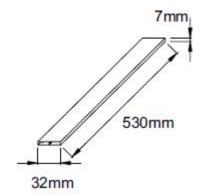
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>θJC</sub>	DC operation	2.0	°C/W
Typical Thermal Resistance, Case to Heat Sink	R <sub>0JS</sub>	DC operation	50	°C/W
Case Style	TO-220AB D <sup>2</sup> PAK TO-262			

### **Tube Specification**

Device	Package	Weight	Shipping
MBR30CT	TO-220AB	1.8g	50pcs / tube
MBRB30CT	D <sup>2</sup> PAK	1.85g	800pcs / reel
MBR30CT-1	TO-262	1.85g	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# Tube Specification(TO-220AB/TO-262)

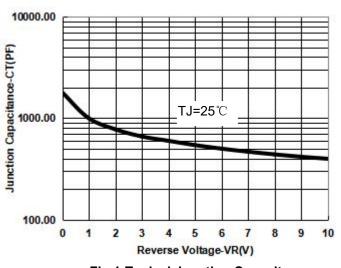








#### **Ratings and Characteristics Curves**



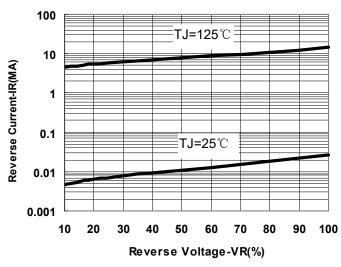


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

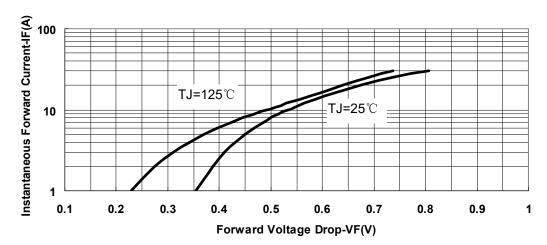


Fig.3-Typical Instantaneous Forward Voltage Characteristics

#### **Marking Diagram** Where XXXXX is YYWWL MBR MBR3035CT-1 = Device Type XXXXX = Package type MBR3035CT 30 = Forward Current (30A) 0 SSG XXXXX MBRB3035CT 35/45 = Reverse Voltage (35/45V) CT -1 = Configuration SSG XXXXX SSG = SSG = Year ww = Week = Lot Number Cautions: Molding resin Epoxy resin UL:94V-0

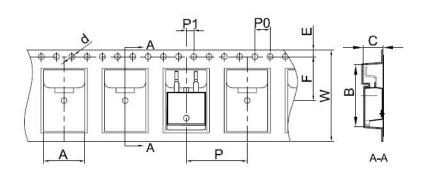
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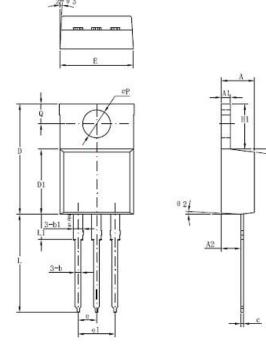


# Carrier Tape Specification D<sup>2</sup>PAK



Symbol	Millimeters		
	Min.	Max.	
Α	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

# **Mechanical Dimensions TO-220AB**



Symbol	Dimensions in millimeters		
	Min	Typical	Max
A	3.56	-	4.83
A1	0.51	-	1.40
A2	2.03	-	2.92
b	0.38	-	1.02
b1	1.14	-	1.78
С	0.31	-	0.61
D	14.22	-	16.51
D1	8.38	-	9.42
E	9.65	-	10.67
е	-	2.54	-
e1	-	5.08	-
H1	5.84	-	6.86
L	12.70	-	14.73
L1	-	-	6.35
ФР	-	3.56	-
Q	2.54	-	3.43

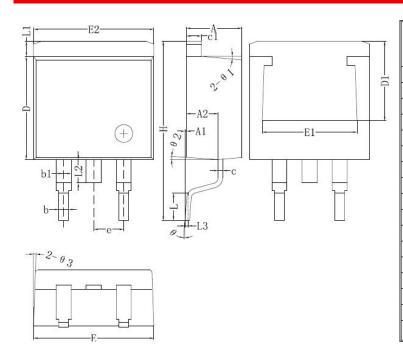
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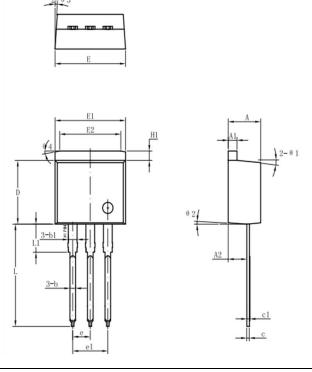


### **Mechanical Dimensions D<sup>2</sup>PAK**



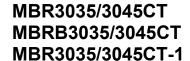
Symbol	Dimensions in millimeters		
<b>- - - - - - - - - -</b>	Min.	Max.	
Α	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
С	0.31	0.74	
c1	1.14	1.65	
D	8.38	8.65	
D1	6.86		
E1	6.22		
E2	9.65	10.67	
е	2.54BSC		
Н	14.60	15.88	
L	1.78	2.80	
L1	<u>-</u>	1.68	
L2	-	1.78	
L3	0.255BSC		
Θ	0	8°	

# **Mechanical Dimensions TO-262**



Symbol	Millimeters			
	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
с1	1.17	1.27	1.37	
D	8.55	8.70	8.85	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.18	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.70	
L1	1.17	1.27	1.40	
L2			2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		4°		
е3		4°		

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